

PRELIMINARY
 Notice: This is not a final specification.
 Some parametric limits are subject to change.

MITSUBISHI RECTIFIER DIODE

FD5000AV-100DA

HIGH-POWER, GENERAL USE
 PRESS PACK TYPE

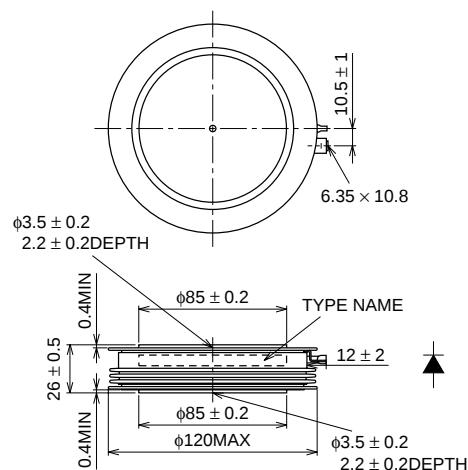
FD5000AV-100DA



- V_{RRM} Repetitive peak reverse voltage 5000V
- $I_F(AV)$ Average forward current 5000A

OUTLINE DRAWING

Dimensions in mm



APPLICATION

High-power inverters

Fly-hwheel diode for GCT Thyristor

Power supplies as high frequency rectifiers

MAXIMUM RATINGS

Symbol	Parameter	Conditions	Voltage class	Unit
V_{RRM}	Repetitive peak reverse voltage	—	5000	V
V_{RSM}	Non-repetitive peak reverse voltage	—	5000	V
$V_R(DC)$	DC reverse voltage	—	2000	V

Symbol	Parameter	Conditions	Ratings	Unit
$I_F(RMS)$	RMS forward current	Applied for all condition angles	7850	A
$I_F(AV)$	Average forward current	$f = 60\text{Hz}$, sinewave $\theta = 180^\circ$, $T_f = 70^\circ\text{C}$	5000	A
I_{FSM}	Surge forward current	One half cycle at 60Hz, $T_j = 150^\circ\text{C}$ start	70	kA
I^2_t	Current-squared, time integration		2.0×10^7	A^2s
T_j	Operation junction temperature		$-40 \sim 150$	$^\circ\text{C}$
T_{stg}	Storage temperature		$-40 \sim 150$	$^\circ\text{C}$
—	Mounting force required	(Recommended value 47kN)	39 ~ 55	kN
—	Weight	Typical value 1450g	—	g

ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V_{FM}	Forward voltage	$I_{FM} = 7000\text{A}$, $T_j = 150^\circ\text{C}$	—	—	1.6	V
I_{RRM}	Repetitive peak reverse current	$V_{RM} = 5000\text{V}$, $T_j = 150^\circ\text{C}$	—	—	200	mA
$R_{th(j-f)}$	Thermal resistance	Junction to Fin	—	—	0.0071	K/W

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PERFORMANCE CURVES

